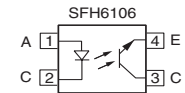
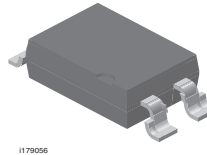
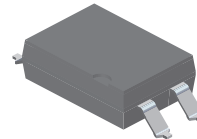
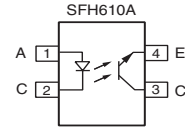
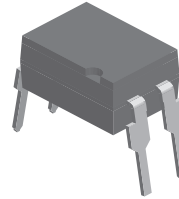


## Optocoupler, Phototransistor Output, High Reliability, 5300 V<sub>RMS</sub>

### Features

- Good CTR Linearity Depending on Forward Current
- Isolation Test Voltage, 5300 V<sub>RMS</sub>
- High Collector-Emitter Voltage, V<sub>CEO</sub> = 70 V
- Low Saturation Voltage
- Fast Switching Times
- Low CTR Degradation
- Temperature Stable
- Low Coupling Capacitance
- End-Stackable, 0.100" (2.54 mm) Spacing
- High Common-Mode Interference Immunity
- Lead (Pb)-free component
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC



### Agency Approvals

- UL1577, File No. E52744 System Code H or J, Double Protection
- DIN EN 60747-5-2 (VDE0884)  
DIN EN 60747-5-5 pending  
Available with Option 1
- CSA 93751
- BSI IEC60950 IEC60065

### Description

The SFH610A (DIP) and SFH6106 (SMD) feature a high current transfer ratio, low coupling capacitance and high isolation voltage. These couplers have a GaAs infrared diode emitter, which is optically coupled to a silicon planar phototransistor detector, and is incorporated in a plastic DIP-4 or SMD package.

The coupling devices are designed for signal transmission between two electrically separated circuits.

The couplers are end-stackable with 2.54 mm spacing.

Creepage and clearance distances of > 8.0 mm are achieved with option 6. This version complies with IEC 60950 (DIN VDE 0805) for reinforced insulation up to an operation voltage of 400 V<sub>RMS</sub> or DC. Specifications subject to change.

### Order Information

Part	Remarks
SFH610A-1	CTR 40 - 80 %, DIP-4
SFH610A-2	CTR 63 - 125 %, DIP-4
SFH610A-3	CTR 100 - 200 %, DIP-4
SFH610A-4	CTR 160 - 320 %, DIP-4
SFH610A-5	CTR 250 - 500 %, DIP-4
SFH6106-1	CTR 40 - 80 %, SMD-4
SFH6106-2	CTR 63 - 125 %, SMD-4
SFH6106-3	CTR 100 - 200 %, SMD-4
SFH6106-4	CTR 160 - 320 %, SMD-4
SFH6106-5T	CTR 250 - 500 %, SMD-4, tape and reel
SFH610A-1X006	CTR 40 - 80 %, DIP-4 400 mil
SFH610A-1X018T	CTR 40 - 80 %, SMD-4, wide leads spread
SFH610A-2X006	CTR 63 - 125 %, DIP-4 400 mil
SFH610A-3X006	CTR 100 - 200 %, DIP-4 400 mil
SFH610A-3X007	CTR 100 - 200 %, SMD-4
SFH610A-4X006	CTR 160 - 320 %, DIP-4 400 mil

For additional information on the available options refer to Option Information.

### Absolute Maximum Ratings

$T_{amb} = 25\text{ °C}$ , unless otherwise specified

Stresses in excess of the absolute Maximum Ratings can cause permanent damage to the device. Functional operation of the device is not implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute Maximum Rating for extended periods of the time can adversely affect reliability.

### Input

Parameter	Test condition	Symbol	Value	Unit
Reverse voltage		$V_R$	6.0	V
DC Forward current		$I_F$	60	mA
Surge forward current	$t \leq 10\ \mu\text{s}$	$I_{FSM}$	2.5	A
Power dissipation		$P_{diss}$	100	mW

### Output

Parameter	Test condition	Symbol	Value	Unit
Collector-emitter voltage		$V_{CE}$	70	V
Emitter-collector voltage		$V_{EC}$	7.0	V
Collector current		$I_C$	50	mA
	$t \leq 1.0\ \text{ms}$	$I_C$	100	mA
Power dissipation		$P_{diss}$	150	mW

### Coupler

Parameter	Test condition	Symbol	Value	Unit
Isolation test voltage between emitter and detector, refer to climate DIN 40046, part 2, Nov. 74		$V_{ISO}$	5300	$V_{RMS}$
Creepage			$\geq 7.0$	mm
Clearance			$\geq 7.0$	mm
Insulation thickness between emitter and detector			$\geq 0.4$	mm
Comparative Tracking index per DIN IEC 112/VDEO 303, part 1			$\geq 175$	
Isolation resistance	$V_{IO} = 500\ \text{V}, T_{amb} = 25\text{ °C}$	$R_{IO}$	$\geq 10^{12}$	$\Omega$
	$V_{IO} = 500\ \text{V}, T_{amb} = 100\text{ °C}$	$R_{IO}$	$\geq 10^{11}$	$\Omega$
Storage temperature range		$T_{stg}$	- 55 to + 150	$^{\circ}\text{C}$
Ambient temperature range		$T_{amb}$	- 55 to + 100	$^{\circ}\text{C}$
Junction temperature		$T_j$	100	$^{\circ}\text{C}$
Soldering temperature	max. 10 s. dip soldering distance to seating plane $\geq 1.5\ \text{mm}$	$T_{sld}$	260	$^{\circ}\text{C}$



## Electrical Characteristics

$T_{amb} = 25\text{ }^{\circ}\text{C}$ , unless otherwise specified

Minimum and maximum values are testing requirements. Typical values are characteristics of the device and are the result of engineering evaluation. Typical values are for information only and are not part of the testing requirements.

## Input

Parameter	Test condition	Symbol	Min	Typ.	Max	Unit
Forward voltage	$I_F = 60\text{ mA}$	$V_F$		1.25	1.65	V
Reverse current	$V_R = 6.0\text{ V}$	$I_R$		0.01	10	$\mu\text{A}$
Capacitance	$V_R = 0\text{ V}$ , $f = 1.0\text{ MHz}$	$C_O$		13		pF
Thermal resistance		$R_{thja}$		750		K/W

## Output

Parameter	Test condition	Part	Symbol	Min	Typ.	Max	Unit
Collector-emitter capacitance	$V_{CE} = 5\text{ V}$ , $f = 1.0\text{ MHz}$		$C_{CE}$		5.2		pF
Thermal resistance			$R_{thja}$		500		K/W
Collector-emitter leakage current	$V_{CE} = 10\text{ V}$	SFH610A-1 SFH6106-1	$I_{CEO}$		2.0	50	nA
		SFH610A-2 SFH6106-2	$I_{CEO}$		2.0	50	nA
		SFH610A-3 SFH6106-3	$I_{CEO}$		5.0	100	nA
		SFH610A-4 SFH6106-4	$I_{CEO}$		5.0	100	nA
		SFH610A-5 SFH6106-5T	$I_{CEO}$		5.0	100	nA

## Coupler

Parameter	Test condition	Symbol	Min	Typ.	Max	Unit
Collector-emitter saturation voltage	$I_F = 10\text{ mA}$ , $f = 1.0\text{ MHz}$	$V_{CEsat}$	0.4	0.25		V
Coupling capacitance		$C_C$		0.4		pF

## Current Transfer Ratio

Parameter	Test condition	Part	Symbol	Min	Typ.	Max	Unit
$I_C/I_F$	$I_F = 10 \text{ mA}, V_{CE} = 5.0 \text{ V}$	SFH610A-1 SFH6106-1	CTR	40		80	%
		SFH610A-2 SFH6106-2	CTR	63		125	%
		SFH610A-3 SFH6106-3	CTR	100		200	%
		SFH610A-4 SFH6106-4	CTR	160		320	%
		SFH610A-5 SFH6106-5T	CTR	250		500	%
	$I_F = 1.0 \text{ mA}, V_{CE} = 5.0 \text{ V}$	SFH610A-1 SFH6106-1	CTR	13	30		%
		SFH610A-2 SFH6106-2	CTR	22	45		%
		SFH610A-3 SFH6106-3	CTR	34	70		%
		SFH610A-4 SFH6106-4	CTR	56	90		%

## Switching Non-saturated

All values presented are typical values

Parameter	Current	Rise time	Fall time	Turn-on tim	Turn-off time	Cut-off frequency
Test condition	$V_{CC} = 5.0 \text{ V}, R_L = 75 \Omega$					$V_{CC} = 5.0 \text{ V}$
Symbol	$I_F$	$t_r$	$t_f$	$t_{on}$	$t_{off}$	$F_{CO}$
Unit	mA	$\mu\text{s}$	$\mu\text{s}$	$\mu\text{s}$	$\mu\text{s}$	kHz
	10	2.0	2.0	3.0	2.3	250

## Switching Saturated

All values presented are typical values

Parameter	Current	Rise time	Fall time	Turn-on time	Turn-off time
Symbol	$I_F$	$t_r$	$t_f$	$t_{on}$	$t_{off}$
Unit	mA	$\mu\text{s}$	$\mu\text{s}$	$\mu\text{s}$	$\mu\text{s}$
SFH610A-1 SFH6106-1	20	2.0	11	3.0	18
SFH610A-2 SFH6106-2	10	3.0	14	4.2	23
SFH610A-3 SFH6106-3	10	3.0	14	4.2	23
SFH610A-4 SFH6106-4	5.0	4.6	15	6.0	25

## Typical Characteristics

$T_{amb} = 25\text{ }^{\circ}\text{C}$ , unless otherwise specified



isfh610a\_01

Figure 1. Linear Operation ( without Saturation)



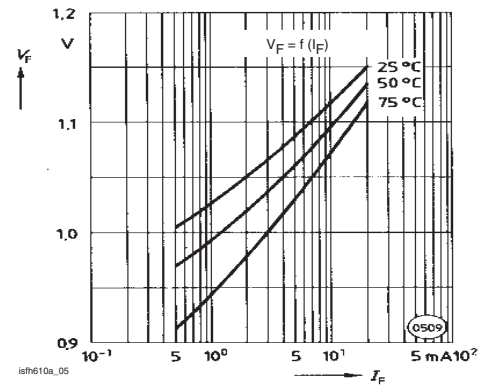
isfh610a\_04

Figure 4. Output Characteristics (typ.) Collector Current vs. Collector-Emitter Voltage



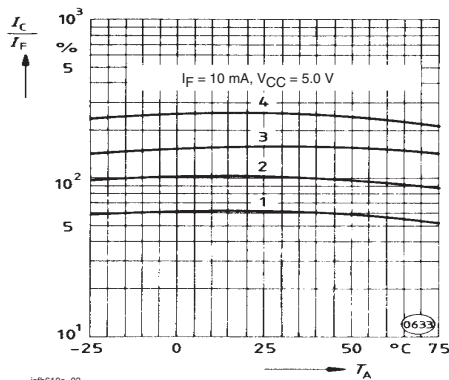
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Figure 2. Switching Operation (with Saturation)



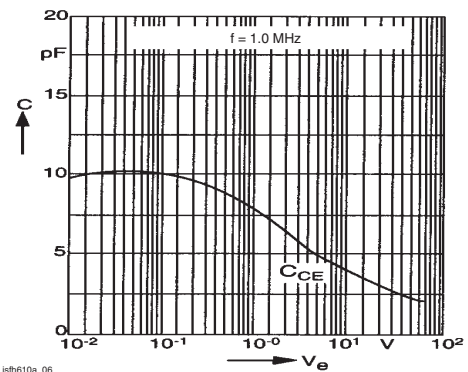
isfh610a\_05

Figure 5. Diode Forward Voltage vs. Forward Current



isfh610a\_03

Figure 3. Current Transfer Ratio (CTR) vs. Temperature



isfh610a\_06

Figure 6. Transistor Capacitance (typ.) vs. Collector-Emitter Voltage

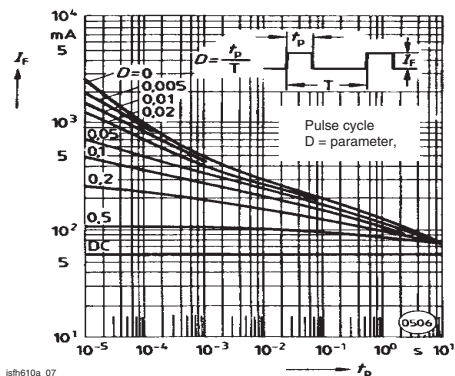


Figure 7. Permissible Pulse Handling Capability Forward Current vs. Pulse Width

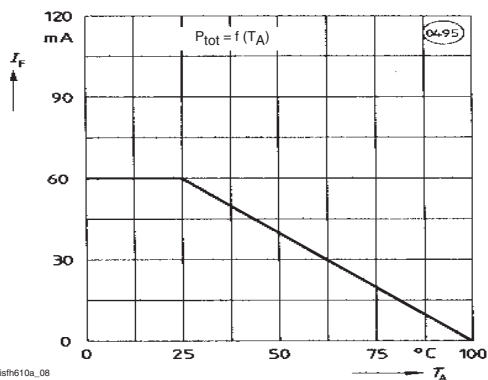


Figure 8. Permissible Power Dissipation vs. Temperature

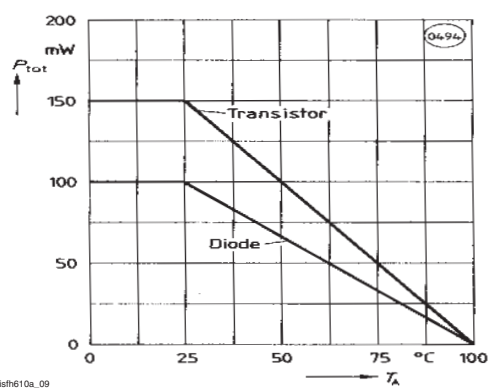
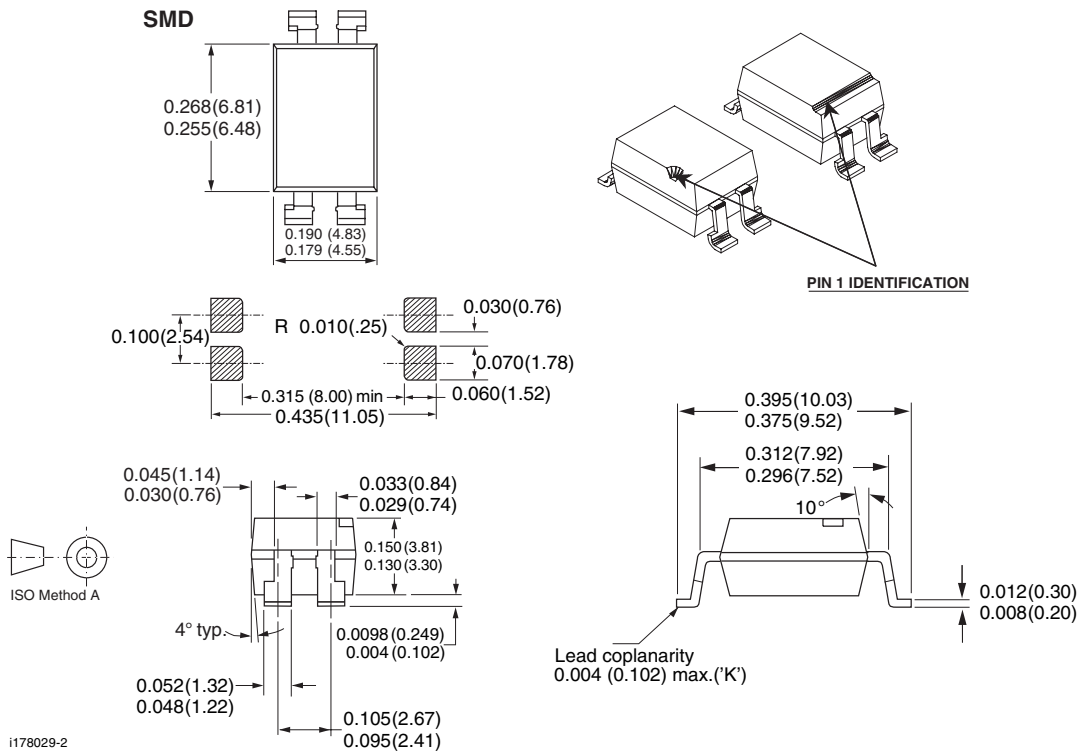


Figure 9. Permissible Diode Forward Current vs. Ambient Temperature

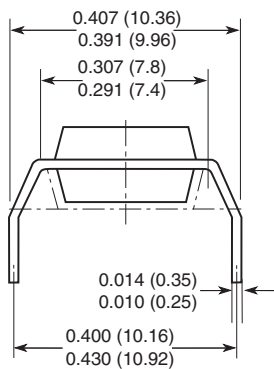
## Package Dimensions in Inches (mm)



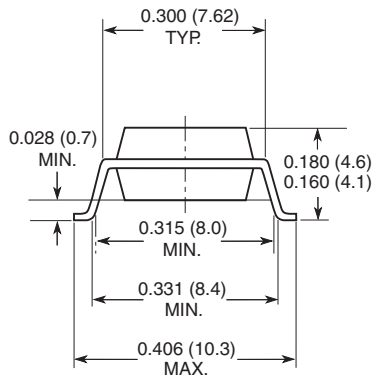
## Package Dimensions in Inches (mm)



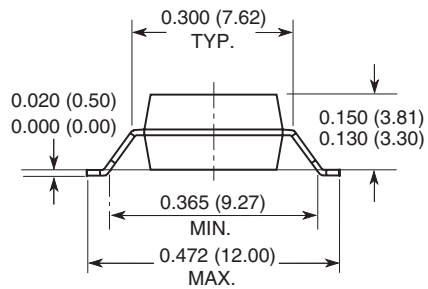
Option 6



Option 7



Option 8



18487





## Ozone Depleting Substances Policy Statement

It is the policy of Vishay Semiconductor GmbH to

1. Meet all present and future national and international statutory requirements.
2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

Vishay Semiconductor GmbH has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively
2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA
3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

Vishay Semiconductor GmbH can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

We reserve the right to make changes to improve technical design and may do so without further notice.

Parameters can vary in different applications. All operating parameters must be validated for each customer application by the customer. Should the buyer use Vishay Semiconductors products for any unintended or unauthorized application, the buyer shall indemnify Vishay Semiconductors against all claims, costs, damages, and expenses, arising out of, directly or indirectly, any claim of personal damage, injury or death associated with such unintended or unauthorized use.

Vishay Semiconductor GmbH, P.O.B. 3535, D-74025 Heilbronn, Germany



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- Подбор аналогов;
- Консультации по применению компонента;
- Поставка образцов и прототипов;
- Техническая поддержка проекта;
- Защита от снятия компонента с производства.



#### Как с нами связаться

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